

# FCP22N60N / FCPF22N60NT N-Channel SupreMOS<sup>®</sup> MOSFET 600 V, 22 A, 165 mΩ

## Features

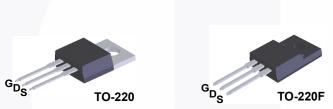
- BV<sub>DSS</sub> > 650 V @ T<sub>J</sub> = 150°C
- R<sub>DS(on)</sub> = 140 mΩ (Typ.) @ V<sub>GS</sub> = 10 V, I<sub>D</sub> = 11 A
- Ultra Low Gate Charge (Typ.  $Q_q = 45 \text{ nC}$ )
- Low Effective Output Capacitance (Typ. Coss(eff.) = 196.4 pF)
- 100% Avalanche Tested
- RoHS Compliant

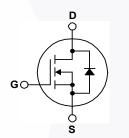
## Application

- LCD/LED/PDP TV
- Lighting
- Solar Inverter
- AC-DC Power Supply

# Description

The SupreMOS<sup>®</sup> MOSFET is Fairchild Semiconductor's next generation of high voltage super-junction (SJ) technology employing a deep trench filling process that differentiates it from the conventional SJ MOSFETs. This advanced technology and precise process control provides lowest Rsp on-resistance, superior switching performance and ruggedness. SupreMOS MOSFET is suitable for high frequency switching power converter applications such as PFC, server/telecom power, FPD TV power, ATX power, and industrial power applications.





## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		Parameter		FCP22N60N	FCPF22N60NT	Unit	
V <sub>DSS</sub>	Drain to Source Voltage			6	00	V	
V <sub>GSS</sub>	Gate to Source Voltage			±	45	V	
	Drain Current	- Continuous ( $T_C = 25^{\circ}C$ )		22	22*	۸	
I <sub>D</sub> Drain Current		- Continuous ( $T_C = 100^{\circ}C$ )		13.8	13.8*	- A	
I <sub>DM</sub>	Drain Current	- Pulsed	- Pulsed (Note 1)		66*	Α	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)			672		mJ	
I <sub>AR</sub>	Avalanche Current		(Note 1)	7.3		А	
E <sub>AR</sub>	Repetitive Avalanche Energy (Note		(Note 1)	2.75		mJ	
du/dt	MOSFET dv/dt			100		V/ns	
dv/dt	Peak Diode Recovery dv	/dt	(Note 3)	20			
D	Dewen Dissingtion	(T <sub>C</sub> = 25°C)		205	39	W	
P <sub>D</sub>	Power Dissipation	- Derate Above 25°C		1.64	0.31	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150		°C		
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			3	00	°C	

\*Drain current limited by maximum junction temperature.

# **Thermal Characteristics**

Symbol	Parameter	FCP22N60N	FCPF22N60NT	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.61	3.2	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	62.5	0/00

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November 2013

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	P22N60N
	/ FCP
	F22N60NT
,	– N-Cha
	N-Channel SupreMOS
	preMOS <sup>®</sup> N
	<sup>®</sup> MOSFE
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# Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCP22N60N	FCP22N60N	TO-220	Tube	N/A	N/A	50 units
FCPF22N60NT	FCPF22N60NT	TO-220F	Tube	N/A	N/A	50 units

## Electrical Characteristics T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	cteristics					
D\/	Drain to Source Breakdown Voltage	I <sub>D</sub> = 1 mA, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 25 <sup>o</sup> C	600	-	-	V
BV <sub>DSS</sub>	Drain to Source Breakdown voltage	I <sub>D</sub> = 1 mA, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 150 <sup>o</sup> C	650	-	-	v
ΔΒV <sub>DSS</sub> / ΔΤ <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 1 \text{ mA}$ , Referenced to 25°C	-	0.68	-	V/ºC
1	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 480 V, V <sub>GS</sub> = 0 V	-	-	10	
IDSS	zero Gale voltage Drain Current	V <sub>DS</sub> = 480 V, T <sub>J</sub> = 125 <sup>o</sup> C	-	-	100	μA
I <sub>GSS</sub>	Gate to Body Leakage Current	$V_{GS}$ = ±45 V, $V_{DS}$ = 0 V	-	-	±100	nA

## **On Characteristics**

V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \ \mu A$	2.0	3.0	4.0	V
R <sub>DS(on)</sub>	Static Drain to Source On Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 11 A	-	0.140	0.165	Ω
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 11 A	-	22	-	S

## **Dynamic Characteristics**

Ciss	Input Capacitance		-	1950	-	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 100 V, V_{GS} = 0 V,$	-	75.9	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1 MHz		3	-	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 380 V, V <sub>GS</sub> = 0 V, f = 1 MHz	-	43.2	-	pF
Coss(eff.)	Effective Output Capacitance	$V_{DS} = 0 V$ to 480 V, $V_{GS} = 0 V$	-	196.4	-	pF
Q <sub>g(tot)</sub>	Total Gate Charge at 10V	V <sub>DS</sub> = 380 V, I <sub>D</sub> = 11 A,	-	45	-	nC
Q <sub>gs</sub>	Gate to Source Gate Charge	$V_{GS} = 10 V$	-	8.7	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge	(Note 4)	-	14.5	-	nC
ESR	Equivalent Series Resistance (G-S)	f = 1 MHz	-	1	-	Ω

## **Switching Characteristics**

t <sub>d(on)</sub>	Turn-On Delay Time		-	16.9	-	ns
t <sub>r</sub>	Turn-On Rise Time	V <sub>DD</sub> = 380 V, I <sub>D</sub> = 11 A	-	16.7	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ = 10 V, $R_{G}$ = 4.7 $\Omega$	-	49	-	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4)	-	4	-	ns

## **Drain-Source Diode Characteristics**

I <sub>S</sub>	Maximum Continuous Drain to Source Diode Forward Current		-	-	22	А
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current		-	-	66	Α
V <sub>SD</sub>	Drain to Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 11 A	-	-	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 11 A	-	350	-	ns
Q <sub>rr</sub>	Reverse Recovery Charge	dI <sub>F</sub> /dt = 100 A/µs	-	6	-	μC

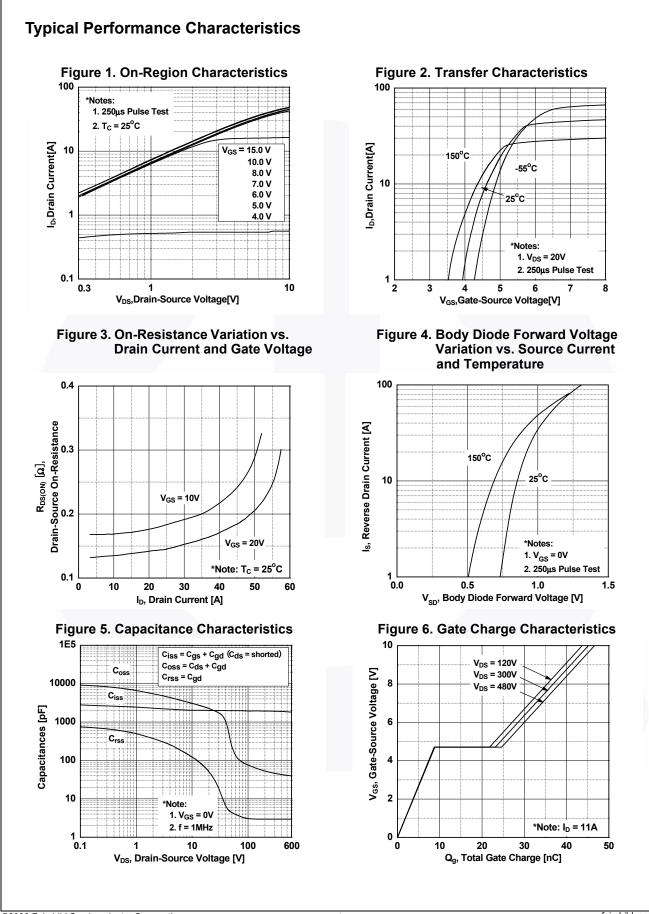
Notes:

1. Repetitive rating: pulse width-limited by maximum junction temperature.

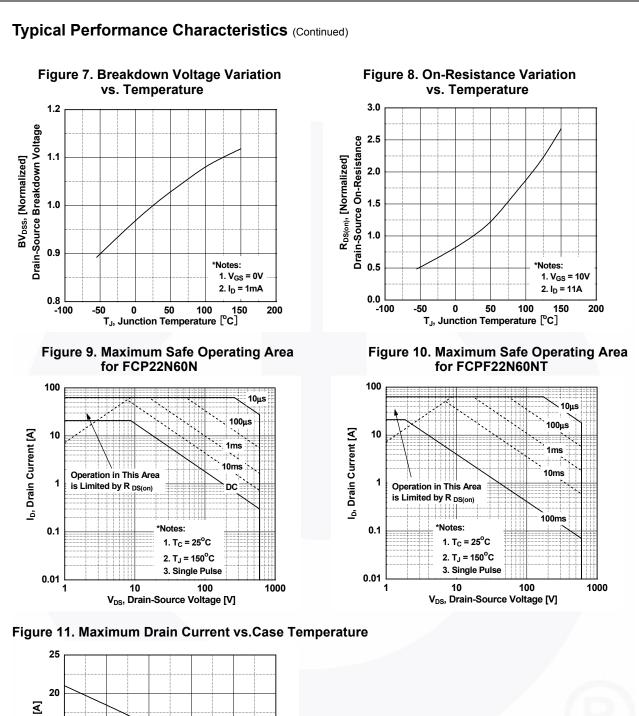
2.  $I_{AS}$  = 7.3 A,  $R_G$  = 25  $\Omega$ , starting  $T_J$  = 25°C.

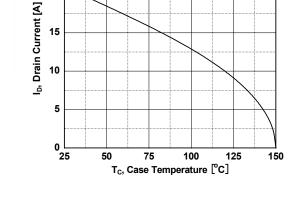
3. I\_{SD}  $\leq$  22 A, di/dt  $\leq$  200 A/µs, V\_{DD}  $\leq$  380 V, starting T\_J = 25°C.

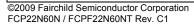
4. Essentially independent of operating temperature typical characteristics.

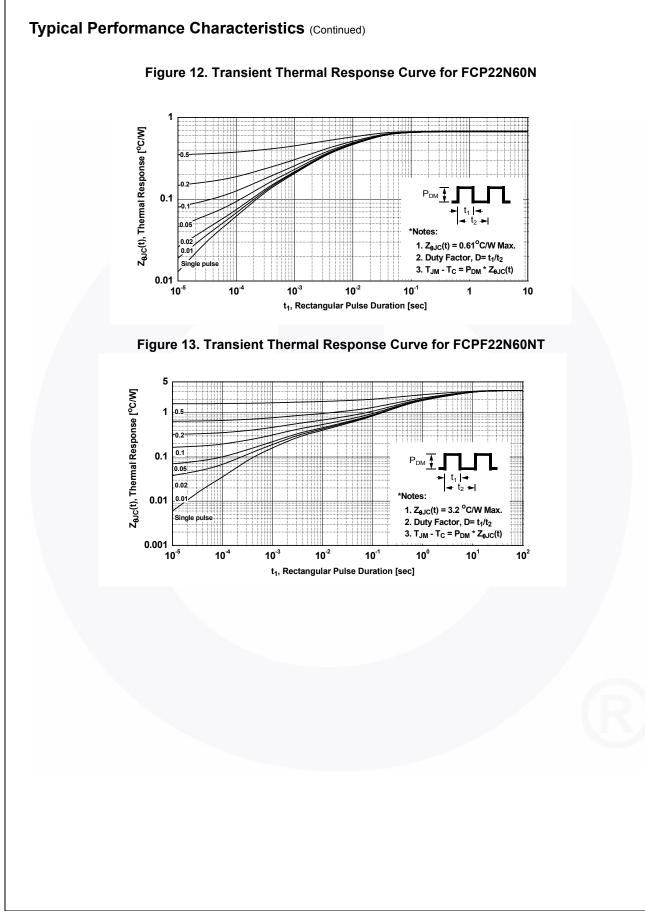


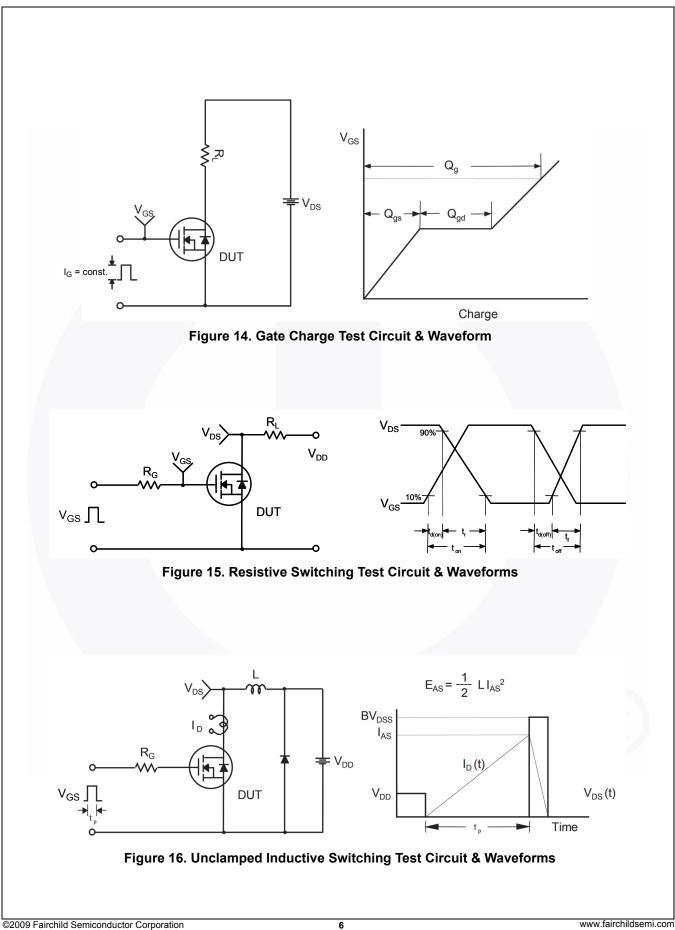
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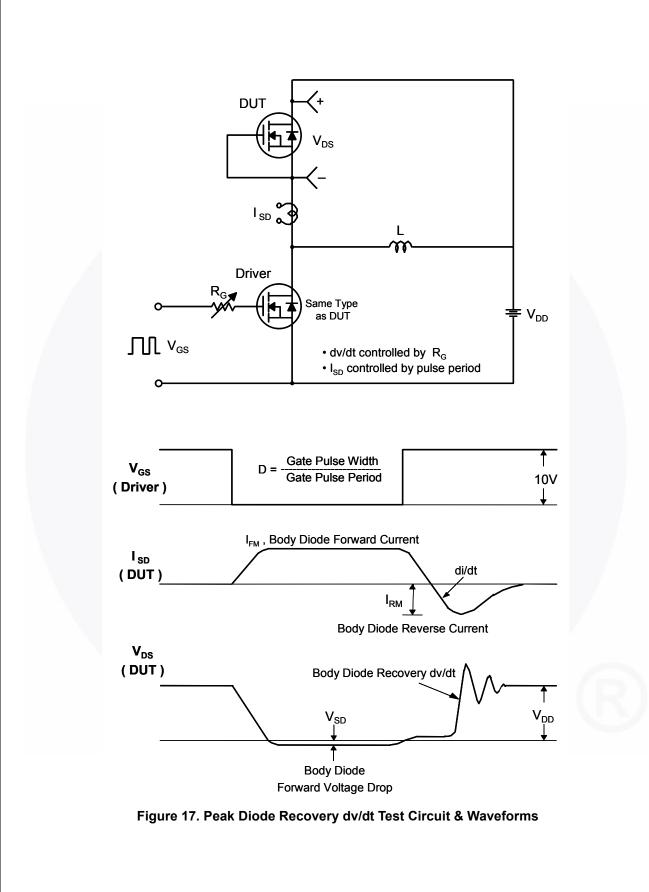


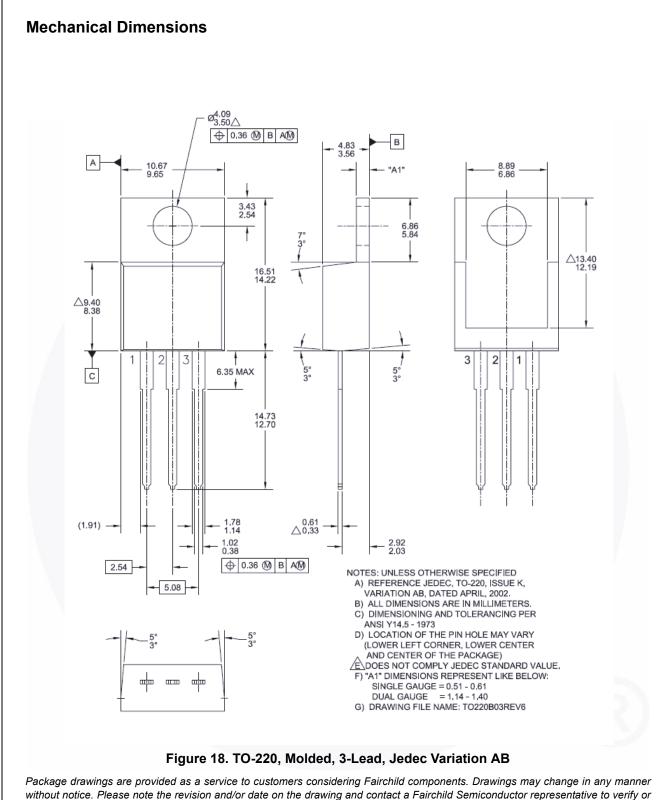






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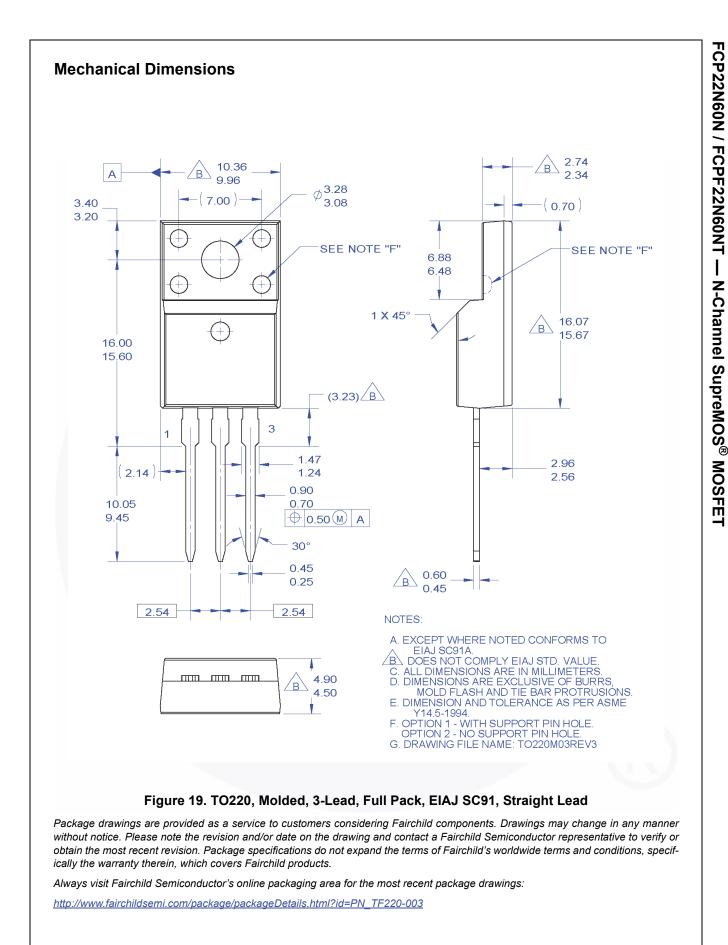
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